Multiscale analytic continuation approach to nanosystem simulation: Applications to virus electrostatics

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Electrostatic effects in nanosystems are understood via a physical picture built on their multiscale character and the distinct behavior of mobile ions versus charge groups fixed to the nanostructure. The Poisson–Boltzmann equation is nondimensionalized to introduce a factor λ that measures the density of mobile ion charge versus that due to fixed charges; the diffusive smearing and volume exclusion effects of the former tend to diminish its value relative to that from the fixed charges. We introduce the ratio σ of the average nearest-neighbor atom distance to the characteristic size of the features of the nanostructure of interest (e.g., a viral capsomer). We show that a unified treatment (i.e., $\lambda \propto \sigma$) and a perturbation expansion around σ =0 yields, through analytic continuation, an approximation to the electrostatic potential of high accuracy and computational efficiency. The approach was analyzed via Padé approximants and demonstrated on viral system electrostatics; it can be generalized to accommodate extended Poisson-Boltzmann models, and has wider applicability to nonequilibrium electrodiffusion and many-particle quantum systems. © 2010 American Institute of Physics. [doi:10.1063/1.3424771]

I. INTRODUCTION

A nanostructure is strongly influenced by electrostatic effects. For example, the capsid of many viruses may undergo structural transition due to changes in pH and salinity. These effects are the result of the strength of Coulomb interactions, but also reflect channeling of the electrical field due to contrasts in dielectric constant ε between the host aqueous medium or membranes and the nanosystem.

The Poisson–Boltzmann (PB) equation has traditionally been used to compute the electrostatic potential around a macromolecule. However, a PB model ignores the volume of ions in the medium. Therefore, the PB equation is only valid for dilute ionic solutions and several angstroms away from the fixed charges on the nanosystem of interest (i.e., concentration ≤ 0.15 M). While the PB equation has been used to model these systems, the million or more atoms in a virus or other nanosystem and its surroundings makes direct PB simulation a challenge. Parameter studies, e.g., to determine virus stability for a range of pH, salinity, and temperature, is made possible via approximations to the complete PB solution. However, our goal is to construct a formalism that allows such parameter studies while retaining the accuracy of a full nonlinear all-atom analysis.

Several approaches and software packages for solving the linear and nonlinear PB equation have been presented throughout the past decade. An overview of numerical techniques commonly applied to PB type equations is provided in Ref. 2. For the linear PB, in one approach the electrostatic potential is expressed as a superposition of basis functions. The electrostatic energy functional is then minimized with respect to the expansion coefficients subject to total charge

conservation. The boundary element method utilizes analytical solutions obtained in terms of Green's functions and discretization on domain surfaces (molecular surfaces) are used to compute the potential in the whole domain for a linear problem. 4,5 One of the most common approaches used to solve the linear and the nonlinear PB equation is the finite difference formulation, where spatial derivatives are approximated using neighboring points.⁶⁻⁸ A successive overrelaxation method yields rapid convergence in solving the linear systems obtained from finite difference discretization.⁶ A finite difference domain decomposition scheme with local correction is used to solve the problem in two dimensions. However, a straightforward extension to three dimensions required $O(N^3 \log N^3)$ computer operations. In comparison, a hybrid of boundary element and finite difference methods combined advantages of both techniques and has been used to study nucleic acid structures. ¹⁰ An indirect way of solving the equation is by reformulating the elliptic PB equation as the long-time solution of an advection-diffusion equation. 11 Adaptive finite element techniques have been used to solve the PB equation for large systems. Potentials in specific regions within a system are calculated using boundary conditions derived from a coarse-grained PB solution over the entire system. This has been implemented in the adaptive PB solver (APBS) using standard focusing techniques with the Bank-Holst algorithm. 12 In this approach, dielectric discontinuity across the molecular surface is captured using a dense adaptive mesh of tetrahedral elements. However, one might argue that in a physically relevant model, the dielectric discontinuity is not present; rather, ε gradually increases to its unperturbed bulk value with distance from the molecule-

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medium boundary.⁸ This allows application of regular grids leading to simple numeric schemes with multigrid implementations.¹³

Multiscale analysis is a powerful methodology that has been applied to a broad spectrum of complex classical ^{14–25} and quantum ^{26–30} many-body systems, and to reaction/ transport/mechanical phenomena in porous media. 31-37 The problems to which it has been applied are usually governed by linear equations, although nonlinear reacting-deforming porous media have been treated through this approach.³⁶ Multiscale analysis has been used to derive rigorous stochastic equations for nanosystem dynamics starting from the classical Liouville equation. ^{38–41} In this paper, we explore an analogous multiscale approach to the PB problem designed for nanosystem applications. Through our formalism, dielectric channeling, and a coarse-grained PB equation, coupling of electrostatic effects across scales in space are captured. We identify characteristic charge densities and lengths which enable the evaluation of various effects as they influence dielectric channeling and coarse-grained electrostatics. For example, coarse-grained potential profiles affect small scale potential fluctuations and conversely. A new effect coarsegrained dielectric anisotropy is identified. The main objective of this paper is to outline our mathematical and conceptual framework. However, implementation of an implied multiscale numerical algorithm is used to validate the theory and shows promise for efficient PB simulation.

We consider a formulation in terms of two parameters σ and λ . The first is the ratio of the average nearest-neighbor atom distance to a characteristic length of a nanoscale feature in the system of interest. The second, λ , is the ratio of a typical single mobile ion charge density at infinity to the average charge density within a charged group fixed to the nanostructure. Our procedure is to recast the σ , λ -parametrized problem in to one, wherein $\lambda \propto \sigma$, and then develop a unified perturbation scheme starting from σ =0 and continuing to the value σ equal to the value of λ of interest. In the following, we reformulate the PB problem in a multiscale fashion and explore a method to construct solutions in the limit of small σ , demonstrating both numerically and analytically the accuracy of this approach.

II. MULTISCALE FORMULATION

Let \vec{r} be position in the system expressed in units such that as one traverses an average nearest-neighbor atom distance, \vec{r} moves a distance of about one (about 1 Å). As \vec{r} traverses the whole nanosystem, it moves a distance of $O(\sigma^{-1})$. By definition, σ is the ratio of the average atomic nearest-neighbor distance to the size of the nanosystem. It is natural to introduce a scaled position $\vec{R} = \sigma \vec{r}$. As one traverses the whole nanosystem, \vec{R} moves a distance of about 1 in its unit (about several nanometers). We construct the electrical potential Φ by making the ansatz that it simultaneously depends on \vec{r} and \vec{R} , and show the smallness of σ allows one to construct the \vec{r} and \vec{R} dependencies simultaneously.

Consider the PB model expressed in the \vec{r} spatial variable

$$\vec{\nabla} \cdot (\varepsilon \vec{\nabla} \Phi) + f = 0, \tag{2.1}$$

where ε is the dielectric constant and f is the charge density. Both f and ε depend on position, reflecting the underlying spatial variation in the atomic scale structure, while they also account for the nanoscale variation in structure (e.g., the size of the nanosystem is roughly σ^{-1}). In our formulation, f is divided into f_d due to discrete charges fixed to the nanosystem and a contribution f_c from mobile charges.

A nondimensionalization of the PB equation reveals a factor that enables the development of a novel approximation scheme. r_c is a length characteristic of the Φ profile. A stationary charge density within the region excluded by a typical fixed ion f_x , a single mobile ion charge density at infinity f_{∞} , the dielectric constant of free space ε_0 , and k_BT/e are other characteristic quantities. With this we define a new set of dimensionless variables indicated by a

"
$$\sim$$
 " via $\vec{r} = r_c \tilde{\vec{r}}$, $\tilde{\vec{R}} = \sigma \tilde{\vec{r}}$, $\Phi = k_B T \tilde{\Phi}/e$,

$$\varepsilon = \varepsilon_0 \tilde{\varepsilon}, \quad f_d = f_x \tilde{f}_d, \quad f_c = f_\infty \tilde{f}_c.$$

As Φ depends on both \vec{r} and \vec{R} by our multiscale ansatz, the chain rule implies, upon letting $\vec{\nabla}_0$ and $\vec{\nabla}_1$ be \vec{r} and \vec{R} gradients, respectively,

$$(\vec{\nabla}_0 + \sigma \vec{\nabla}_1) \cdot [\ \varepsilon(\vec{\nabla}_0 + \sigma \vec{\nabla}_1)\Phi)] + f_c(\vec{R}, \vec{r}, \Phi) + f_d(\vec{R}, \vec{r}) = 0. \eqno(2.2)$$

Some details on the derivation of Eq. (2.2) are provided in Appendix A. With this, the multiscale ansatz Eq. (2.2) and introduction of the dimensionless variables, the multiscale PB equation becomes

$$(\widetilde{\nabla}_{0} + \sigma \widetilde{\nabla}_{1}) \cdot [\widetilde{\varepsilon}(\widetilde{\nabla}_{0} + \sigma \widetilde{\nabla}_{1})\widetilde{\Phi})] + \lambda \widetilde{f}_{c}(\widetilde{R}, \widetilde{r}, \widetilde{\Phi}) + \widetilde{f}_{d}(\widetilde{R}, \widetilde{r}) = 0,$$

$$(2.3)$$

where $\lambda = r_c^2 f_{\infty} e / \varepsilon_0 k_B T$ and $r_c^2 = \varepsilon_0 k_B T / f_x e$.

Dropping the " \sim " for simplicity, this yields

$$(\vec{\nabla}_0 + \sigma \vec{\nabla}_1) \cdot \left[\varepsilon (\vec{\nabla}_0 + \sigma \vec{\nabla}_1) \Phi) \right] + \lambda f_c(\vec{R}, \vec{r}, \Phi) + f_d(\vec{R}, \vec{r}) = 0.$$
 (2.4)

The objective is to construct $\Phi(R,\vec{r},\sigma,\lambda)$ via parameter unification and analytic continuation. Typical values of factors in the expression for λ at biological conditions (see Table I) imply that λ ranges from 10^{-2} to 10^{-3} . For many nanosystems, σ lie in the same range. Therefore, we suggest a methodology where λ is set equal to σ to achieve a unified perturbation methodology. We proceed in a perturbative fashion to construct Φ along the line $\lambda = \sigma$, continuing perturbatively from the (σ,λ) origin to the λ value of interest. With this, we seek a small σ perturbative solution to the following equation:

$$\begin{split} (\vec{\nabla}_0 + \sigma \vec{\nabla}_1) \cdot \left[\ \varepsilon (\vec{\nabla}_0 + \sigma \vec{\nabla}_1) \Phi) \right] + \sigma f_c(\vec{R}, \vec{r}, \Phi) + f_d(\vec{R}, \vec{r}) = 0. \end{split} \label{eq:continuous} \tag{2.5}$$

The above decomposition of charge is based on the notion that the fixed charges are well-localized and thereby

TABLE I. List of universal and system-specific parameters used in calculation.

Universal parameters	Values	Equation	Reference
Maximum dielectric ε_m	4	(4.6)	11 and 56
Minimum dielectric ε_{atom}	80	(4.6)	11 and 56
Dielectric transition width	5 Å	(4.5) and (4.6)	8, 11, and 56
System specific parameters			
рН	7		11 and 56
f_x	$10^{-2}e\text{Å}^{-3}$	(4.3) and (4.4)	This paper, 64
Fine grid spacing	0.3–0.9 Å	(2.2)– (2.4)	This paper
Coarse grid spacing	20–22 Å	(2.2)– (2.4)	This paper
Temperature T	298.5 K	(2.2)– (2.4)	This paper
Salinity C_i^{∞}	0.125 M	(3.2) and (3.6)	65

creates a high charge density. In contrast, the mobile ions are highly fluctuating and thereby have an effectively more diffuse charge distribution and correspondingly lower charge density. In addition, the excluded volume effect on mobile ion distribution around fixed charges prevents excessive counter-ion accumulation. In contrast, if there were no excluded volume then the counter-ion charge density would mirror that of the fixed charges. However, observations of correlation functions in dense media support the notion that mobile ion density is diffusive in nature for a large number of problems with 1:1 electrolyte and hence can be treated perturbatively (as discussed further in Sec. VI).

While the original PB Eq. (2.1) masks the multiscale character of the nanosystem problem, the reformulated one makes σ explicit. For a million-atom nanosystem such as a small virus, σ is roughly 10^{-2} . Hence, one expects that solutions to Eq. (2.5) can be constructed as a Taylor series in σ

$$\Phi = \sum_{n=0}^{\infty} \Phi_n(\vec{R}, \vec{r}) \sigma^n. \tag{2.6}$$

This theme is developed in Sec. III.

III. MULTISCALE PERTURBATION ANALYSIS

Consider details of the development of the potential as a Taylor series in σ as suggested in the previous section. Using Eq. (2.6) and analyzing the multiscale PB equation order-by-order, we construct Φ . For arbitrary \vec{r} -dependent function A, we define the linear operator \hat{P} such that

$$\hat{P}A = \vec{\nabla}_0 \cdot (\varepsilon \vec{\nabla}_0 A). \tag{3.1}$$

To $O(\sigma^0)$ in the multiscale perturbation series, one obtains $\hat{P}\Phi_0+f_d(\vec{R},\vec{r})=0$. This implies Φ_0 can be obtained in the form $\Phi_0=\Phi^*(\vec{R})+\theta(\vec{R},\vec{r})$, where θ satisfied $\hat{P}\theta+f_d(\vec{R},\vec{r})=0$. Since f_d is independent of Φ , θ can readily be obtained via a linear numerical solver. Note that Φ and Φ_0 vanishes for the isolated nanosystem in an infinite medium as $|\vec{r}|\to\infty$. Here, Φ^* captures the \vec{R} dependent variations in the zeroth order solution. It stays constant over changes on the angstrom scale. Hence, $\hat{P}\Phi^*(\vec{R})=0$. The behavior of the contribution Φ^* to Φ_0 is addressed via an analysis of the problem to higher order.

To $O(\sigma)$, one obtains

$$\hat{P}\Phi_1 + \vec{\nabla}_0 \cdot (\varepsilon \vec{\nabla}_1 \Phi_0) + \vec{\nabla}_1 \cdot (\varepsilon \vec{\nabla}_0 \Phi_0) + f_{c(0)}(\Phi_0, \vec{R}, \vec{r}) = 0,$$
(3.2)

where $f_{c(0)}$ is the coefficient of order $O(\sigma^0)$ when expanding f_c in σ and depends on Φ_0 as shown in Sec. IV.

We define b to be the solution of

$$\hat{P}b_{\alpha} + \partial \varepsilon / \partial r_{\alpha} = 0, \quad \alpha = 1, 2, 3, \tag{3.3}$$

where b_{α} and r_{α} are the α th Cartesian components of b and \vec{r} . It arises in a manner similar to the formulation of flow in porous media where the analog to \vec{b} yields the permeability tensor. Linearity of Eq. (3.2) and the definition of \vec{b} implies the equation $\Phi_1 = \vec{b} \cdot \vec{\nabla}_1 \Phi^* + \psi$, where ψ is a solution to

$$\hat{P}\psi + \vec{\nabla}_0 \cdot (\varepsilon \vec{\nabla}_1 \theta) + \vec{\nabla}_1 \cdot (\varepsilon \vec{\nabla}_0 \theta) + f_{c(0)}(\Phi_0, \vec{R}, \vec{r}) = 0. \quad (3.4)$$

A more detailed derivation of the above is shown in Appendix B

Let
$$b_{\alpha} = c_{\alpha} - r_{\alpha}$$
. Then

$$\hat{P}c_{\alpha} = 0. \tag{3.5}$$

Since Φ_1 must be bound as $|\vec{r}| \to \infty$, b_α must be bound there for a nanosystem in an infinite medium. Thus, the auxiliary quantity $c_\alpha \to r_\alpha$ as $|\vec{r}| \to \infty$. This provides the asymptotic condition needed to determine c_α , and thus b_α . For the class of problems of interest, $\Phi \to 0$ as \vec{r} and \vec{R} go to infinity, which is ensured to $O(\sigma)$ via the above asymptotic conditions. Finally, ψ vanishes as $|\vec{r}| \to \infty$ and b_α is nonzero and has angstrom scale variations near and within the nanosystem in response to variations in ε . This completes the $O(\sigma)$ analysis.

To
$$O(\sigma^2)$$

$$\hat{P}\Phi_2 + \vec{\nabla}_1 \cdot (\varepsilon \vec{\nabla}_1 \Phi_0) + \vec{\nabla}_0 \cdot (\varepsilon \vec{\nabla}_1 \Phi_1) + \vec{\nabla}_1 \cdot (\varepsilon \vec{\nabla}_0 \Phi_1) + f_{c(1)}(\vec{r}, \vec{R}, \Phi_0, \Phi_1) = 0, \tag{3.6}$$

where $f_{c(1)}$ is the coefficient of $O(\sigma)$ when expanding f_c in σ about σ =0. As a consequence, $f_{c(1)}$ depends on both Φ_0 and Φ_1 , as shown in Sec. IV.

An equation for Φ^* is obtained as follows. First, a weight is introduced $W(\vec{r}, \vec{R})$ that samples \vec{r} space in the vicinity of a point $\vec{r}_0^* = \sigma^{-1} \vec{R}$. Equation (3.6) is multiplied by $W(\vec{r}, \vec{R})$, integrated over \vec{r} , and using the boundary conditions at infinity, one finds

$$\vec{\nabla}_{1} \cdot \left[\bar{\varepsilon} * \vec{\nabla}_{1} \Phi^{*} \right] + \langle \vec{\nabla}_{1} \cdot (\varepsilon \vec{\nabla}_{0} \psi) \rangle + \langle \vec{\nabla}_{1} \cdot (\varepsilon \vec{\nabla}_{1} \theta) \rangle$$

$$+ f_{c(1)}^{*} (\vec{R}, \Phi_{0}, \Phi_{1}) = 0, \qquad (3.7)$$

where

$$f_{c(1)}^*(\vec{R}, \Phi_0, \Phi_1) = \langle f_{c(1)} \rangle, \quad \langle A \rangle \equiv \int d^3 r W(\vec{r_0} - \vec{r}) A, \quad (3.8)$$

$$\varepsilon_{\alpha\alpha'}^* = \langle \varepsilon \rangle \delta_{\alpha\alpha'} + \left\langle \varepsilon \frac{\partial b_{\alpha'}}{\partial r_{\alpha}} \right\rangle, \tag{3.9}$$

$$W(\vec{r}, \vec{R}) = N \exp - \{\sigma(\vec{r}_0^* - \vec{r})^2 / \Delta^2\}.$$
 (3.10)

N is a normalization constant. The coarse-grained dielectric factor $\vec{\hat{\epsilon}}^*$ is a tensor. Its profile across the nanosystem, and the directionality it creates because of its tensorial character, accounts for large-scale channeling. This anisotropy follows from an averaging of the potential response to short-scale dielectric variations as shown above. b_{α} serves as a response function underlying the effective dielectric tensor. In arriving at this result, we have ignored $\langle \vec{\nabla}_0 \cdot (\epsilon \vec{\nabla}_0 \Phi_2) \rangle$ via arguments provided in Appendix C. The coarse-grained PB Eq. (3.7) yields the long-scale background potential profile Φ^* across the system.

The resolution of the coarse-grained PB equation is determined by the width $\Delta \sigma^{-1/2}$ of W. The width of W is taken to be much greater than the short length scale (i.e., the average nearest-neighbor atom distance of about 1 Å) but much smaller than the size of the features we wish to resolve (e.g., a viral capsomer), allowing the function to die out beyond the integrating volume, i.e., at distances of several nanometers away from \vec{r}_0^* . The form of W is discussed further in Appendix C. As Φ_0 captures all the short-scale features directly related to the nanosystem via θ , and Φ_1 captures them via b and ψ , our multiscale approach retains both short-scale and long-scale behaviors. Thus, our approach is not a semiphenomenological method that requires recalibration with each new application. While the auxiliary quantities b, ψ , and θ must be computed at atomic resolution, the linearity of the equations they satisfy, unlike for the original PB equation, is readily solved numerically. This adds to the great efficiency of our methodology which retains both long-scale and short-scale variations, relegating the nonlinearity to a coarse-grained equation for Φ^* . Even though the coarsegrained potential Φ^* is only R-dependent, the charge density remains multiscale in nature and hence, short-scale structure of the potential is accounted for in θ and Φ_1 . Φ_1 , in particular, accounts for local correction to the smooth background potential Φ^* . Solutions to Eqs. (3.4) and (3.7) are essentially coupled, yielding an interscale feedback loop that computes the smooth background potential Φ^* and the local correction Φ_1 simultaneously. We validate the perturbation scheme via computational implementation, and in particular show that $\Phi_0 > \sigma \Phi_1 \gg \sigma^2 \Phi_2$. The interscale feedback relationship implied by the above development is summarized in Fig. 1.

IV. DETAILED PHYSICAL FORMULATION

The detailed physical formulation of the PB model adopts integrated notions from our earlier work¹¹ and that of others.⁴³ Mobile ion concentrations are assumed to be at equilibrium. Let C_l and μ_l be the concentration and chemical potential of mobile ions of type l, $l=1,2,\cdots,L$. We adopt the phenomenological model

$$\mu_{l} = \mu_{l}^{*} + k_{B}T \ln(\gamma_{l}^{-1}C_{l}) + z_{l}F\Phi \tag{4.1}$$

for activity coefficient γ_l^{-1} and reference potential of l, μ_l^* , and Faraday constant F. Given that far from the nanosystem $\Phi \to 0$ and $C_l \to C_l^{\infty}$, and that μ_l is constant across the system at equilibrium, then

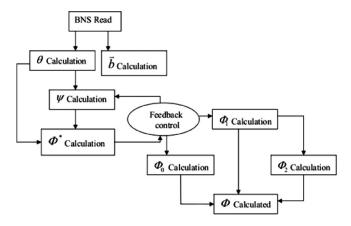


FIG. 1. Interscale feedback loop implied by the perturbation analysis.

$$C_I = \gamma_I C_I^{\infty} e^{-Fz_I \Phi / k_B T}. \tag{4.2}$$

With this, the charge density from the mobile ions is given by

$$f_c = \sum_{l=1}^{L} \gamma_l z_l F C_l^{\infty} e^{-F z_l \Phi / k_B T}.$$
 (4.3)

To simulate the excluded volume effect that prohibits the unphysical overlap of the mobile ions with the nanosystem atoms, γ_l is taken to be one except near an atom fixed to the nanosystem $(i=1,2,\cdots,N)$. $i(\vec{r})$ is the identity of the nanosystem atom closest to \vec{r} and $\vec{r}_{i(\vec{r})}$ is the location of the atom $i(\vec{r})$. With this,

$$\gamma_l = g(|\vec{r} - \vec{r}_{i(\vec{r})}|/(a_i + b_l), \Lambda_{il}), \tag{4.4}$$

where Λ_{il} is a dimensionless transition width parameter for the i, l pair.

$$g(\chi_{il}, \Lambda_{il}) = \begin{cases} 0, \chi_{il} \le 1 \\ \min_{i=1, \dots, N} \{1 - e^{-\Lambda_{il}^2 (\chi_{il} - 1)^2}\}, \chi_{il} > 1 \end{cases}, \quad (4.5)$$

where $\chi_{il} = |\vec{r} - \vec{r}_{i(\vec{r})}|/(a_i + b_l)$, a_i is the radius of nanosystem atom i, and b_l is the radius of mobile ion l. With this the mobile ion excluded layer has a thickness of $(a_i + b_l)$. This phenomenology describes a smooth transition in ion accessibility from 0 to 1 is suggested in other studies, ^{44–48} the basis of which is fluctuating positions of the fixed and mobile ions, as well as the continuous profile of electron density around a given ion. The mean displacement of an ion from an equilibrium position was considered to be $>0.1(a_i+b_l)$ Å. ⁴⁹ This displacement decides the choice of transition width parameter Λ_{il} . In this way, the charge density around the fixed ions is taken to be Gaussian in form. The half-width of the Gaussian is the atomic radius of the fixed ion.

The continuous charge density is expressed as a Taylor expansion of f_c in σ about σ =0.

$$\begin{split} f_c &= f_c\big|_{\Phi_0} + \left. \frac{\partial f_c}{\partial \Phi} \right|_{\Phi_0} (\Phi - \Phi_0) + \frac{1}{2} \left. \frac{\partial^2 f_c}{\partial^2 \Phi} \right|_{\Phi_0} (\Phi - \Phi_0)^2 \\ &+ \cdots \\ &= f_c\big|_{\Phi_0} + \left. \frac{\partial f_c}{\partial \Phi} \right|_{\Phi_0} (\sigma \Phi_1 + \sigma^2 \Phi_2 + \cdots) \\ &+ \frac{1}{2} \left. \frac{\partial^2 f_c}{\partial^2 \Phi} \right|_{\Phi_0} (\sigma \Phi_1 + \sigma^2 \Phi_2 + \cdots)^2 + \cdots \\ &= f_c\big|_{\Phi_0} + \sigma \left[\left. \frac{\partial f_c}{\partial \Phi} \right|_{\Phi_0} \right] \Phi_1 \\ &+ \sigma^2 \left[\frac{1}{2} \Phi_1^2 \left. \frac{\partial^2 f_c}{\partial^2 \Phi} \right|_{\Phi_0} + \Phi_2 \left. \frac{\partial f_c}{\partial \Phi} \right|_{\Phi_0} \right] \cdots \\ &= f_{c(0)} + \sigma f_{c(1)} + \cdots . \end{split}$$

Nondimensionalizing the above implied

$$\begin{split} \widetilde{f}_c &= \widetilde{f}_{c(0)} + \sigma \widetilde{f}_{c(1)} + \cdots . \\ \text{Thus} \quad & f_c^{\infty} \widetilde{f}_{c(0)} = \sum_{l=1}^L \gamma_l z_l F C_l^{\infty} e^{-F z_l \Phi_0 / k_B T} \quad \text{and} \quad & f_c^{\infty} \widetilde{f}_{c(1)} \\ &= -\Phi_1 \sum_{l=1}^L \gamma_l (z_l F)^2 / k_B T C_l^{\infty} e^{-F z_l \Phi_0 / k_B T}. \end{split}$$

Dropping " \sim ", the above expressions for $\tilde{f}_{c(0)}$ and $\tilde{f}_{c(1)}$ were used in Eqs. (3.2) and (3.6). Unlike methods where the partitioning of charges is according to their spatial locations, ¹⁰ in our method it is according to the order in σ to which they contributed to charge density. Developing an algorithm with spatial partitioning might lead to more efficient computation as fewer grid points can be considered for solving the linear equations, although this was not attempted in this study. The mobile ion charge densities $\tilde{f}_{c(0)}$ and $\tilde{f}_{c(1)}$ are multiscale in nature, i.e., they simultaneously account for rapidly varying short-scale fluctuations and a slowly varying background potential.

The dielectric constant distribution ε (τ, Λ_{il}) is calculated using the formula

$$\varepsilon(\tau, \Lambda_{il}) = \begin{cases} \varepsilon_{\text{atom}}, \tau \leq 1\\ \min_{i=1,\dots,N} \{\varepsilon_m + (\varepsilon_{\text{atom}} - \varepsilon_m)e^{-\Lambda_{il}^2(\tau - 1)^2}\}, \tau > 1 \end{cases}$$
(4.6)

where ε_m and $\varepsilon_{\text{atom}}$ are the dielectric constants of the host medium and an nanosystem atom, respectively, and a_s being the solvent atom radius $\tau = |\vec{r} - \vec{r}_{i(\vec{r})}|/(a_i + a_s)$. 11

V. MULTISCALE COMPUTATIONS

The algorithm of the previous sections was implemented as a software package denoted PBms. The utility of our multiscale PB approach depended on the computational requirements for determining \vec{b} , θ , ψ , and Φ^* . The quantities \vec{b} , θ , and ψ satisfied linear equations with Dirichlet conditions, i.e., \vec{b} , θ , and ψ were zero at the boundary of the simulation domain, assumed far from the nanosystem. Thus, solving for these variables did not require the costly iteration needed to solve the original nonlinear PB problem. However, solving the interscale equations to simultaneously calculate Φ^* and ψ

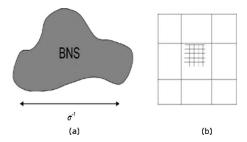


FIG. 2. (a) A nanostructure (nanosystem) of size of $O(\sigma^{-1})$ containing millions of atoms is shown. A multiscale approach that accounts for the distinct length scales involved is developed for solving the PB problem. (b) Schematic discretization showing the coarse grid on which the coarse-grained potential profile Φ^* is solved, and the fine grid on which \vec{b} , θ , and ψ are solved.

was found to require some iteration. Additional overhead arose from the computation of \vec{b} and θ . In our workflow, the solution to the linear PB equation was used as a guess for Φ_0 to initialize the multiscale iterations. Though reasonable for biomolecular systems, 50,51 this slightly added to the time overhead.

The two-grid method used to implement the interscale iteration is suggested in Fig. 2. The coarse-grained PB equation for Φ^* involves a characteristic length, i.e., the nanosystem size, and not the atomic scale. For a small virus [e.g., cowpea chlorotic mottle virus (CCMV), human rhinovirus, poliovirus, and human papillomavirus], the large scale is roughly 100 times larger in length than the size of an atom. Thus, one could simulate the system with a factor of roughly 10^6 fewer grid points when using the coarse-grained equation for Φ^* than for the full PB equation. It is shown below that the central processing unit time for our multiscale method increased more slowly with the number of grid points than did current PB approaches.

In Fig. 3, a schematic flowchart of our multiscale PB simulation approach is presented. To implement this workflow, we used the MUDPACK software to solve the linear equations for b, θ , and ψ and to initialize the multiscale iteration using Gauss-Seidel pointwise relaxation followed by the deferred correction scheme. 52 Modules were written to use \vec{b} to construct the coarse-grained dielectric constant tensor $\vec{\hat{\epsilon}}^*$ and set up the nonlinear coarse-grained PB equation, solved with the alternating direction implicit (ADI) method. 11 A list of parameters used in the course of the simulation is shown in Table I. There are universal parameters that are applicable over a large array of nanosystems. In addition, there are system-specific parameters that must be tailored to the system of interest. In this study, nanosystem atom radius a_i and partial charge were assigned using the CHARMM22 force field.

VI. RESULTS AND DISCUSSIONS

We have demonstrated the accuracy of PBms via numerical experiments, comparison with analytical solution, and results from another solver. Analytical solution is available for the case of a charged planer electrode in 1:1 electrolyte. Here,

FIG. 3. Flow chart showing steps involved in the multiscale computational algorithm.

$$\Phi(u) = 2 \ln \left[\frac{1 + \tanh(\zeta/4) \exp^{-|u|}}{1 - \tanh(\zeta/4) \exp^{-|u|}} \right].$$
 (6.1)

 ζ is the surface potential on the plate and u=kx, where x is the distance along the normal to the plate and k^{-1} is the Debye length. The plate is located at x=0. Since Eq. (6.1) holds for an infinite plate and the simulation was carried out for a finite one, the comparison was made along a normal in the X-direction emanating from the center of the plate to avoid edge effects. Figure 4 shows the PBms generated potential profile along with the analytical solution at $\zeta = 10KT/e$, $C_l^{\infty} = 0.125$ M and grid spacing of 0.5 Å for a square plate with sides of 100 Å. The PBms generated profile is in excellent agreement with the analytical solution. However, one expects deviations from observed near surface profiles because the model used does not account for the Stern layer.

A uniformly charged solid spherical particle of 100 Å radius and a total charge of +750e was considered immersed in a 0.125 M 1: 1 electrolyte. To validate our algorithm, we compared our results for this simple system with that of APBS. ¹² To minimize differences from numerical schemes in solving the linear equations, APBS was used as a linear solver instead of MUDPACK. Similarly to maintain consistency in the underlying physical model, the dielectric constant ε (using pdie: 4; sdie: 80; and srfm: smol) and nanosystem charge distribution f_d (using chgm: spl2) were also

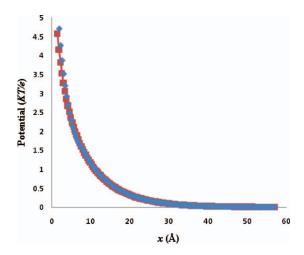


FIG. 4. The PBms generated potential profile (\spadesuit) along with the analytical solution (\blacksquare) for a 100×100 Å² charged plate in 0.125 M 1:1 electrolyte, $\zeta = 10KT/e$ and with 0.5 Å grid spacing.

taken from APBS for both calculations. The ion accessibility was considered smoothly transitional as in Eq. (4.5) for both programs due to reasons mentioned later in this section. The multiscale modified charge density arrays for $[\vec{\nabla}_0 \cdot (\epsilon \vec{\nabla}_1 \theta)$ $+\vec{\nabla}_1 \cdot (\varepsilon \vec{\nabla}_0 \theta) + f_{c(0)}(\Phi_0, \vec{R}, \vec{r})$] appearing in Eq. (3.4) were read back into APBS via the OpenDX format (using "read" and "usemap" options). However, our ADI software was used to solve Eq. (3.7) in PBms. Finally the potential was taken to be zero at the boundary of the domain for both the programs. The root mean square deviation (RMSD) between potentials from direct and multiscale methods is shown in Fig. 5. It is small and decreases with grid spacing. The PBms and APBS-generated potential profiles across the ions accessible region where $\gamma_l \neq 0$ (about 25 Å wide) at 0.6 Å grid spacing (449³ grid size) is shown in Fig. 6(a). The profiles are in good agreement. The ions accessible region (in Fig. 6) begins at a distance of 1.8 Å from the sphere surface due to reasons mentioned below. The boundaries were set at a distance of about 25 Å from the sphere and the potential at the boundary was set to zero since the latter was much greater than the Debye length from the edge of the sphere. The po-

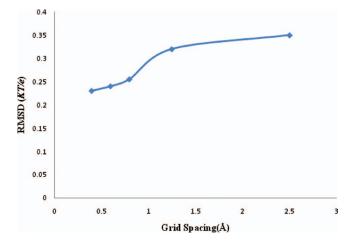


FIG. 5. rms deviations between the PBms and APBS calculated potential distributions for a spherical particle of 100 Å radius and +750e charge in 0.125 M 1:1 electrolyte at different grid spacings.

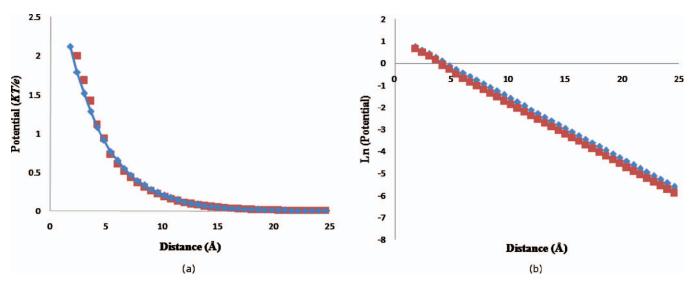


FIG. 6. (a) Potential profile from the surface of the spherical particle (zero on X-axis) to the boundary of the domain (\sim 25 Å form the surface) using APBS (\spadesuit) and PBms (\blacksquare) at 0.6 Å grid spacing along a ray through the center of the sphere. (b) Profile of $\ln(\Phi)$ along the ray as in frame (a) within the same ions accessible region using APBS (\spadesuit) and PBms (\blacksquare).

tential showed a continuous transition across the spheresolution interphase even without imposing continuity there. This is attributable to the second-order differential nature of the PB equation and the smooth nature of the ions accessibility transition (Sec. IV) used for the comparison. The model, and hence the comparison, therefore, does not account for the counter-ions in the Stern (tight bound) layer, i.e., the Stern Layer (of thickness equal to the bare ion radius⁵³ 1.81 Å for Cl⁻ ion) is considered ion excluded with $\gamma_1 = 0.53,54$ In fact, as discussed later, under conditions where counter-ion concentration in Stern layer becomes important the perturbation series tend to diverge. The formalism is applicable to diffusive counter-ions. However, negligible tight binding is expected under conditions chosen for the comparison (a relatively low stationary charge density and 1:1 electrolyte).⁴⁷ Our software can be implemented for nonzero surface boundary conditions with minimal alteration. To magnify differences, the potential profiles in Fig. 6(a) are replotted on a logarithmic scale in Fig. 6(b). Even on the latter scale, PBms and APBS-generated profiles are seen to be in excellent agreement.

Another important aspect of our algorithm is the rapid convergence of multiscale iterations. This is because $\Phi^*(R)$, being a coarse-grained potential, is smoother in nature than fine-scale potentials like θ or ψ . This facilitated the convergence of solutions to the coupled Eqs. (3.4) and (3.7), avoiding cascade error. The long-scale character of $\Phi^*(R)$ is also attributable to the "low frequency" global coupling of the elliptic problem and hence, solving for $\Phi^*(R)$ can be accomplished on a coarse grid.⁴³ To illustrate this, define the error in Eq. (3.4) from the *n*th iteration as $E(\psi_n) = \hat{P}\psi_n$ $+\vec{\nabla}_0 \cdot (\varepsilon \vec{\nabla}_1 \theta) + \vec{\nabla}_1 \cdot (\varepsilon \vec{\nabla}_0 \theta) + f_{c(0),n}(\Phi_0, \vec{R}, \vec{r})$. The equation is solved if $E(\psi_n)=0$. ψ_n and $f_{c(0),n}$ are potential and modified continuous charge density at the *n*th iteration, respectively. In Fig. 7, we plot RMSD of ψ_n from successive multiscale iterations for the solid sphere in solution at 0.6 Å resolution under physical conditions same as those in the previous paragraph. The RMSD after the 15th loop was on the order of $10^{-3}KT/e$ with $E(\psi_n)$ on the order of 10^{-4} . The average ψ_{15} was many orders of magnitude higher, reaching a maximum value of approximately $10^4KT/e$ in regions close to the center. Thus, after 15 iterations, the solution was extremely well converged for this system. Numerical error in solving the equation $\hat{P}\Phi_0+f_d=0$ is plotted as a function of grid spacing in Fig. 8. Errors decreased with reduction in grid spacing. The convergence test of the perturbation series was done to the second-order and it was found that $\Phi_0 > \sigma \Phi_1 \gg \sigma^2 \Phi_2$, validating our approach. Like all perturbation schemes, global convergence is not guaranteed. Only under suitable conditions the series converges. However, the limits of convergence are found to be within the limits of applicability of the physical model (as shown below).

Our multiscale numerical algorithm yielded a highly efficient approach for solving the PB equation. The speed-up over APBS obtained for our algorithm is shown as a function of grid spacing in Fig. 9(a). Comparisons of calculation time for the spherical particle with that of APBS was done on a single Xeon processor using a Dell Power edge system. For 513³ grids, the PBms solver was found to be approximately

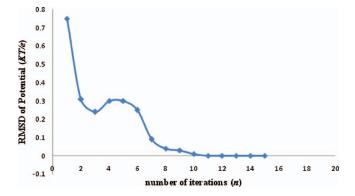


FIG. 7. rms deviation of ψ between consecutive multiscale iterations (n and n+1) as a function of n for the sphere in solution.

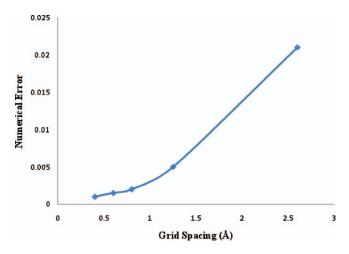


FIG. 8. Numerical error in solving the $O(\sigma^0)$ equation vs grid spacing.

seven times faster than APBS. Figure 9(b) shows the absolute difference in computational times between APBS and PBms as a function of grid spacing. The numbers were fitted to an exponential trend line $y=1122e^{-5.51x}$. This shows the PBms efficiency increases nonlinearly with decrease in grid spacing. A comparison of memory consumption is shown in Fig. 10. This implies that our PBms implementation requires much lesser memory than APBS and is attributable to differences in numerical schemes (i.e., our integration of MUD-PACK solver into the multiscale algorithm). Figures 9 and 10 show that as grid spacing decreases, PBms performance relative to APBS increases. This is realized because a great deal of iterative nonlinear PBms computations occurs at the coarse-grained level. This is somewhat offset by our need for interscale iterations. However, there is a net improvement in performance relative to carrying out nonlinear iterations at the fine grid level only. Another advantage is discussed below in the context of parameter studies.

PBms with MUDPACK and ADI was used to determine the electrostatic potential of CCMV capsid with its 432 210 at-

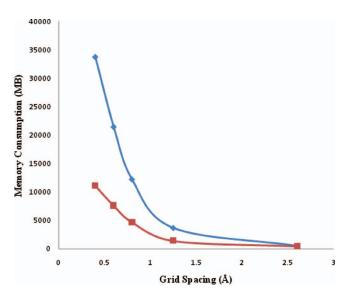


FIG. 10. Memory footprint comparison for Fig. 9(a).

oms. Figures 11 and 12 show the +1KT/e and -1KT/e electrostatic potential isosurfaces for native and swollen CCMV capsid in 0.125 M NaCl solution at 0.7 Å resolution. These isosurfaces were essentially identical to their APBSgenerated counterparts shown in the same figure. To obtain an unambiguous comparison, the nanosystem charge and dielectric distribution were obtained from APBS (as before), and boundary values of the potential in both cases were set to zero. The electrostatic potential isosurface residing near the outer surface of the capsid was predominantly negative except for positive zones concentrated at the margins of hexameric and pentameric subunits, and clearly showed the icosahedral symmetry of the capsid. Cut-away views of the swollen and native states showed the inner surface is primarily positive in nature. This is due to basic amino acid residues that facilitate complexing to the negatively charged RNA. However, in the swollen state, negative patches ap-

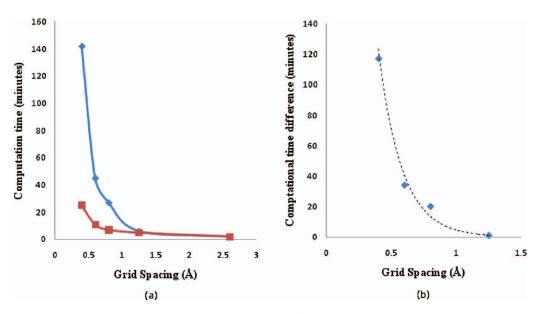


FIG. 9. (a) Plot of computation time vs grid spacing for a spherical particle of 100 Å radius and +750e charge in 0.125 M 1:1 electrolyte using APBS (♦) and PBms (■). (b) Absolute difference in computation time vs grid spacing (<1.5 Å) for computations as in frame (a).

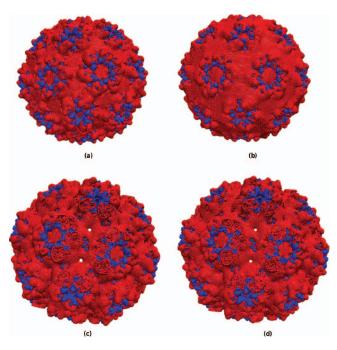


FIG. 11. +1KT/e (blue) -1KT/e (red) potential isosurfaces for the native and swollen state of the 432 120 atom CCMV capsid immersed in 0.125 M NaCl at 0.7 Å resolution, computed via rigorous multiscaling; external view native [(a) PBms; (b) APBS] and swollen [(c) PBms; (d) APBS].

peared on the inner surface. This latter electrostatic distribution promotes RNA release from the capsid core. The physical picture is in agreement with previous results on CCMV, but PBms took less computation time. The APBS-generated isosurfaces shown in this paper, though similar, are not identical to those reported by Konecny *et al.* This is attributable to differences in grid size, boundary conditions, ions accessibility, and ionic strength used for our APBS calculations. However, such differences did not affect the comparison shown in Figs. 11 and 12.

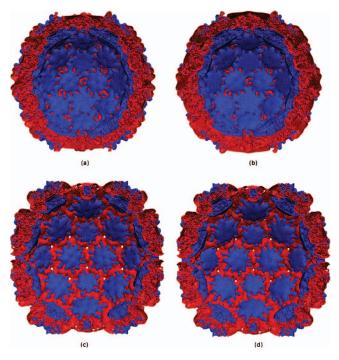


FIG. 12. As in Fig. 11, except for cut-away view.

To illustrate how the multiscale perturbation technique worked, the contributions to the potential of various orders in σ were considered. Two-dimensional potential profiles on an equatorial slice through CCMV for $\sigma\psi$, Φ^* , and $(\Phi^* + \sigma\Phi_1)$ constructed by first multiplying these variables with γ_l to remove fixed ion core variations for illustrative purposes are shown in Fig. 13. $\sigma\psi$, and Φ^* are plotted on the same scale in Figs. 13(a) and 13(b), respectively, to identify the smoothness in variation in the latter. It is seen that $\sigma\Phi_1$ dresses the coarse-grained potential Φ^* variation with atomic scale details to yield a full multiscale counter-ion potential [Fig. 13(c)].

A quantitative analysis of the above results is shown in Table II. The rms deviations between PBms and APBS calculated potentials observed for native and swollen CCMV were an order of magnitude smaller then the corresponding $\langle \Phi_0 \rangle$, showing the PBms calculated results are close to those of APBS. The rms deviations were found to become even smaller, about $10^{-2}KT/e$, when the APBS linear solver was used with multiscaling. This RMSD was smaller than that of the spherical particle at the same grid size validating that the multiscale ansatz worked better as the system grew in size, making the two scales more distinct, as one might have expected. In accordance with results for the simple case of a sphere in solution, differences were expected to further diminish at finer grid spacing.

Table II shows that for CCMV $|\langle \Phi_0 \rangle| > \sigma |\langle \Phi_1 \rangle|$ $\gg \sigma^2 |\langle \Phi_2 \rangle|$, demonstrating the rapid convergence of the multiscale perturbation series. PBms was also used to calculate the electrostatic potential for ubiquitin. Being small, in this system the two scales were less widely separated, making $\sigma \approx 0.1$. Under such conditions, the multiscale ansatz failed as expected, i.e., $\langle \Phi_0 \rangle$ is comparable to the RMSD between PBms and APBS. In addition, the rate of convergence also decreased relative to that for the CCMV results. In summary, the multiscale algorithm is ideal for accurate, efficient simulation of large, complex systems. Only to allow a fare comparison for all the above examples, APBS-generated dielectric distribution was used. Henceforth all calculations are done using the continuous dielectric model in Eq. (4.6) as suggested in Refs. 8, 11, and 56.

Consider the effect of ions accessibility γ_l on the behavior of the method. Omnipresent fluctuations in the atomic configuration imply that γ_l should be transitional, and notably should involve a transition width, as mentioned in Sec. IV. However, to assess the robustness of our method, we explored varying the transition width from 0 to 2.5 Å, finding that the method did not converge when the transition width is less than a cut-off value, roughly 0.5 Å. It did converge for a transition width of 1 Å, the value used in all the above simulations, and certainly for higher transition widths. This issue is closely related to the tight binding of counterions and becomes more relevant in regions of high fixed ion charge density, e.g., in nucleic acids or ribosomal electrostatics. Accurate description of such tightly binding counter-ions (Stern layer) is beyond the scope of PB or other mean field theory. 49 However, previous studies showed nucleic acids in dilute NaCl solution did not display tight binding of counter-ions. 49 Thus, the entire counter-ion charge density 174112-10

FIG. 13. Potential profiles on an equatorial slice through CCMV for (a) $\sigma\psi$, (b) Φ^* (plotted on the same scale as $\sigma\psi$), and (c) $(\Phi^* + \sigma\Phi_1)$ under same conditions as Figs. 11 and 12.

was diffusive, even for such systems. This diffusive nature of mobile ions permitted incorporation of a transition width in ions accessibility and allowed application of the perturbative approach to nucleic acid electrostatics in dilute 1:1 electrolyte. In a 2:1 electrolyte, tight binding of counter-ions to nucleic acid was significant; hence, application of PB theory was not appropriate. PB theory was also known to fail in accurately describing the electrostatics of triplex DNA in 1:1 electrolyte for similar reasons.⁵⁷

To investigate this idea, the RNA part of satellite tobacco mosaic virus (STMV)-RNA complex was chosen. Figure 14 shows the different modes of ions accessibility transition and their corresponding effect on the convergence of the perturbation series calculated to third order for 0.125 M NaCl solution at 0.3 Å grid spacing. Convergence failed when the transition width was less than 0.5 Å. As $\theta(\vec{r}, \vec{R})$ is independent of γ_l and $\Phi^*(\vec{R})$ is insensitive to small scale changes in transition width, the zeroth order solution Φ_0 varied negligibly with γ_l . Hence, it is not incorporated in Fig. 14. Since the fluctuations in ions occurred over a length scale of $>0.1(a_i+b_l)$ Å (>0.7 Å in the present case), a transition width of

1 Å could safely characterize the diffusive counter-ion charge distribution for STMV-RNA electrostatics. To illustrate this, we calculated the total diffusive counter-ion charge per nucleotide over a solvent accessible volume defined by Chen *et al.*⁴⁹ using 1 Å transition width, 0.125 M NaCl solution, and 0.3 Å grid spacing. We found a net Na⁺ charge of +0.82*e*. This was in fair agreement with the reported value of 0.76*e*.⁴⁹ Inclusion of higher order terms will enhance the agreement. This number became +0.46*e* per nucleotide when the potential for the entire complex was calculated, signifying partial neutralization of the negatively charged RNA by the positively charged capsid core. The maximum counterion concentration reached 23.7 M which lies within the reported cut-off of 20–30 M for RNA simulation.⁵⁸

Comparison of predictions of our methodology on large protein assemblies (i.e., viral capsids), as discussed above, illustrated the viability of the approach in a given range of the ions accessibility transition width. However, to explore the potential breakdown of our approach, reformulating our results as the Padé approximants was considered.⁵⁹ Padé approximants have been used to detect anomalous behavior in

TABLE II. Quantitative comparison showing RMSD of PBms results with those of APBS, along with the absolute value of arithmetic mean ($|\langle \rangle|$) of $O(\sigma^0)$, $O(\sigma)$, and $O(\sigma^2)$ PBms solutions for three different systems.

System	RMSD(KT/e)	$ \langle \Phi_0 \rangle (KT/e)$	$ \langle \sigma \Phi_1 \rangle (KT/e)$	$ \langle \sigma^2 \Phi_2 \rangle (KT/e)$
CCMV (Swollen)	0.387	6.773	0.0341	5.077×10^{-3}
CCMV (Native)	0.457	10.04	0.0901	7.439×10^{-3}
Ubiquitin	0.371	0.528	0.0613	4.072×10^{-5}

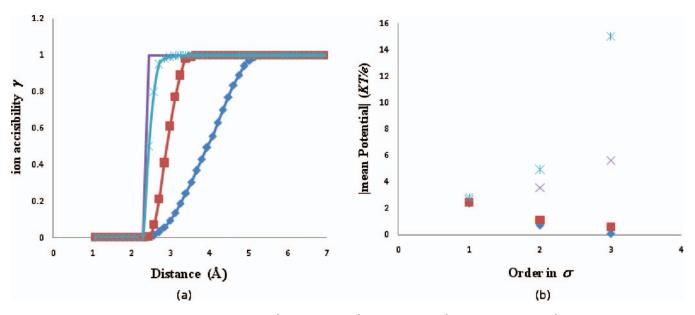


FIG. 14. Effect of ions accessibility transition width (a) 2.5 Å, $\Lambda_{il}=1$ (\spadesuit); 1 Å, $\Lambda_{il}=10$ (\blacksquare); 0.5 Å, $\Lambda_{il}=1000$ (\times); and 0 Å (line) on (b) convergence of perturbation series implied by changes in $|\langle \sigma \Phi_1 \rangle|$, $|\langle \sigma^2 \Phi_2 \rangle|$, and $|\langle \sigma^3 \Phi_3 \rangle|$, where $|\langle \Phi_0 \rangle| = 21.92 KT/e$.

perturbative solutions of various problems (e.g., phase transitions and nonlinear reaction-diffusion phenomena). Padé approximants were traditionally ratios of polynomials, but other analytical forms have been used. ^{17,60} In the present context, we used information from the small σ perturbative analysis to seek anomalies in $\Phi(\vec{r}, \vec{R}, \sigma)$.

For example, we constructed Φ in the form

$$\frac{a_0 + a_1 \sigma}{b_0 + b_1 \sigma} \tag{6.2}$$

for factors a_0 , a_1 , b_0 , and b_1 . However, examination of the multiscale PB equation for large σ showed that Φ must vanish as σ^{-1} as $\sigma \rightarrow \infty$; this implied a_1 is 0. Without loss of generality, we took b_0 =1. Comparison with the σ expansion from the perturbation series of Sec. II, we obtained

$$a_0 = \Phi_0, \quad b_1 = \frac{-\Phi_1}{\Phi_0}.$$
 (6.3)

With this, we found that the Padé approximant had no anomalous behavior for the physical regime of small σ , when $\sigma\Phi_1 < \Phi_0$, implying $\sigma b_1 < 1$.

More general approximants should be examined in the search for possible anomalous behavior. Consider the approximant

$$\Phi = \frac{a_0 + a_1 \sigma}{1 + b_1 \sigma + b_2 \sigma^2},\tag{6.4}$$

which has the correct large σ behavior as $\sigma \rightarrow \infty$

To compute the four a, b coefficients, the σ perturbation series was carried out to third order. This yielded

$$a_0 = \Phi_0, \quad a_1 = b_1 \Phi_0 + \Phi_1, \quad b_1 = \frac{\Phi_0 \Phi_3 - \Phi_1 \Phi_2}{\Phi_1^2 - \Phi_0 \Phi_2},$$

$$(6.5)$$

$$b_2 = -\frac{\Phi_2 + b_1 \Phi_1}{\Phi_0}.$$

Setting the denominator of Eq. (6.4) to zero, one find poles at locations σ_{\pm} given by $\sigma_{\pm} = -b_1 \pm \sqrt{b_1^2 - 4b_2/2b_2}$. We examined this result for RNA in the STMV-RNA complex. Expressions from Eq. (6.5) were used with our computed numerical values of Φ_0 , Φ_1 , Φ_2 , and Φ_3 for the RNA. The location of the poles in the complex σ plane for two different transition widths and all grid nodes in the simulation domain are summarized in Figs. 15 and 16. For a transition width of 1 Å, the nearest pole residing on the positive real σ axis was at $\sigma_{\pm} = 0.128$. For zero transition width, the nearest real positive pole was shifted to about 10^{-6} . Thus, for the former case, poles were absent in the range $\sigma = 0$ to $\sigma \rightarrow \lambda$. This validated analytic continuation of Φ over the chosen range of σ which was further implied by convergence of the perturbation

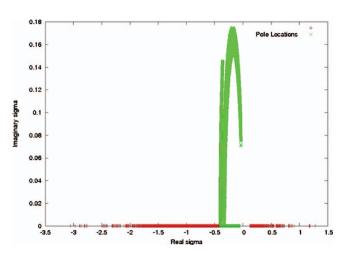


FIG. 15. Location of poles σ_{\pm} in the complex σ plane using 1 Å ions accessibility transition width to determine Φ .

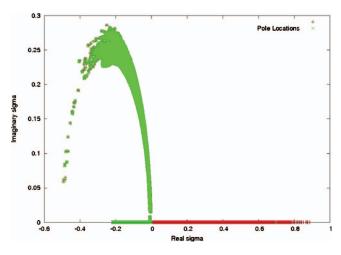


FIG. 16. Location of poles σ_{\pm} in the complex σ plane using 0 Å ions accessibility transition width to determine Φ .

series. Whereas for zero width, poles existed around $\sigma = \lambda$, implying Φ could not be analytically continued over the same σ range. Physically, this means counter-ion overcrowding due to a zero transition width in ion accessibility lead to perturbative corrections as large as the zeroth order potential, suggesting a divergence.

Padé approximants also set a range for the choice of electrolyte concentrations over which the methodology can be applied. The real positive pole nearest to the origin limits the maximum value of C_l^{∞} to $C_{l,\text{max}}^{\infty}$. For $C_l^{\infty} > C_{l,\text{max}}^{\infty}$ one find poles along the real positive σ axis to the left of λ so that analytic continuation from the complex σ origin breaks down. Using σ_{\pm} =0.128 (from the RNA simulation with ions accessibility transition width 1 Å), $C_{l,\text{max}}^{\infty}$ =2.42 M. At this high concentration neither PB theory nor analytic continuation are applicable. The present multiscale methodology directly couples the choice of length scales with the choice of salinity. Extent of local averaging is correlated with salinity via the σ dependence of W. Thus physical conditions (e.g., salinity and temperature) fix the coarse-grained dielectric distribution and interscale feed-back, so that the multiscale PB analysis is carried out self-consistently with automated implementation. Single PBms calculation efficiency at fixed grid spacing facilitates parameter study (e.g., salinity dependence of nanosystem electrostatics). For comparable computational cost of one APBS calculation, multiple PBms runs is possible over a permissible range of salinity. This is achievable due to the advantages of a multiscale algorithm over that of a single scale.

To demonstrate the viability of PBms on an even bigger system, we calculated the electrostatic potential isosurfaces of Simian virus 40 (SV40). It had 1 908 060 atoms and a diameter of about 500 Å. Isosurfaces of $\pm 1KT/e$ obtained at a 0.9 Å resolution for this virus are shown in Fig. 17. In experimental studies, it was found SV40 has seven pentamers forming a cluster with a hexavalent one surrounded by six others. This symmetry was reflected in the location of Glu330 and Glu160 at the Ca²⁺ binding sites. Figure 17(c) shows the -35KT/e isosurface of SV40. This electrostatic potential distribution is consistent with the observed distribution of Ca²⁺ binding sites shown in Fig. 17(d). The

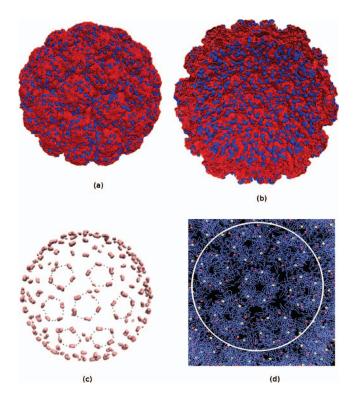


FIG. 17. +1KT/e (blue) -1KT/e (red) potential isosurfaces for SV40 capsid immersed in 0.125 M NaCl computed using PBms; (a) external view; (b) cut-away view; (c) the -35KT/e (pink) isosurface, black dots are used to represent the hexavalent symmetry of the potential distribution; and (d) Ca^{2+} binding sites on the SV40 surface.

highly negative electrostatic potential in these sites supports strong cation binding there, which suggests that PBms facilitated the discovery of electrostatic interaction sites.

VII. CONCLUSIONS

An efficient numerical method for calculating the electrostatic potential based on multiscale analysis was validated. Our methodology enabled the simulation of large supramolecular assemblies, making electrostatic simulation of complex systems such as nucleic acids and viruses possible in reasonable time and using limited computational resources. The accuracy of our results to $O(\sigma^2)$ justified the multiscale ansatz and the decomposition of the charge density. We demonstrated convergence and probed conditions under which the theory breaks down using a Padé approximant analysis to reveal anomalies in the complex length scale ratio (σ) plane. The approach was demostrated on CCMV, STMV, and SV40. As with other field theoretic approaches, the method is expected to break down for tight binding problems such as involving complexes of divalent ions and RNA. However, the scaling approach could be applied to extended PB models which incorporate corrections for tight binding (Stern layer)⁴⁹ and finite ion size.⁶² Accuracy and efficiency of the method are realized for systems with well separated characteristic lengths (e.g., the average nearest-neighbor atom distance versus the overall size of a nanostructure). One of the advantages of the approach is that it automatically generates the σ (and hence salinity) dependence of the potential, thereby allowing for efficient parameter studies. The theory

revealed biologically relevant details on structural features such as the location of calcium binding sites on SV40 pentamers

Even though the theory was developed and implemented for two scales, it can be generalized to account for additional scales. We believe our PBms solver is a valuable asset for solving a variety of bionanosystem electrostatics problems. For example, it could be used to solve Poisson's equation coupled to reaction transport laws for the mobile ions to simulate time-dependent phenomena. The speed-up of PBms could be improved via use of other linear solvers to compute \vec{b} , θ , and ψ and by optimizing various aspect of the PBms workflow (notably parallelization). PBms will be compatible with standard graphics and molecular manipulation codes.

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APPENDIX A: DERIVATION OF THE MULTISCALE PB EQUATION

For simplicity, first consider the PB equation in one dimension. Equation (2.1) in one dimension becomes

$$\frac{d}{dx}\left(\varepsilon\frac{d}{dx}\Phi(x)\right) + f(x) = 0. \tag{A1}$$

In light of the argument given in Sec. II, the dependence of Φ is assumed to be $\Phi(X,x)$, where $X = \sigma x$. Therefore

$$d\Phi(X,x) = \frac{\partial \Phi(X,x)}{\partial x} \bigg|_{X} dx + \frac{\partial \Phi(X,x)}{\partial X} \bigg|_{x} dX,$$

$$\frac{d\Phi(X,x)}{dx} = \left. \frac{\partial\Phi(X,x)}{\partial x} \right|_{X} + \left. \frac{\partial\Phi(X,x)}{\partial X} \right|_{x} \frac{dX}{dx}.$$

As $X = \sigma x$.

$$\frac{d\Phi(X,x)}{dx} = \left. \frac{\partial\Phi(X,x)}{\partial x} \right|_{X} + \sigma \left. \frac{\partial\Phi(X,x)}{\partial X} \right|_{x}. \tag{A2}$$

Making similar calculations for the PB equation, one obtains the multiscale PB equation in one dimension

$$\left(\frac{d}{dx} + \sigma \frac{d}{dX}\right) \left[\varepsilon \left(\frac{d}{dx} + \sigma \frac{d}{dX}\right) \Phi(x) \right] + f(X, x) = 0.$$
 (A3)

Since the total charge density f can be written as a sum of discrete f_d and continuous f_c densities, Eq. (A3) becomes

$$\left(\frac{d}{dx} + \sigma \frac{d}{dX}\right) \left[\varepsilon \left(\frac{d}{dx} + \sigma \frac{d}{dX}\right) \Phi(x) \right] + f_c(X, x, \Phi)$$

$$+ f_d(X, x) = 0. \tag{A4}$$

Extending Eq. (A4) in three dimensions yields Eq. (2.2)

$$(\vec{\nabla}_0 + \sigma \vec{\nabla}_1) \cdot [\ \varepsilon (\vec{\nabla}_0 + \sigma \vec{\nabla}_1) \Phi)] + f_c(\vec{R}, \vec{r}, \Phi) + f_d(\vec{R}, \vec{r}) = 0,$$
(A5)

where

$$\vec{\nabla}_0 = \hat{i} \frac{\partial}{\partial x} + \hat{j} \frac{\partial}{\partial y} + \hat{k} \frac{\partial}{\partial z}, \quad \vec{\nabla}_1 = \hat{i} \frac{\partial}{\partial X} + \hat{j} \frac{\partial}{\partial Y} + \hat{k} \frac{\partial}{\partial Z},$$

for $\vec{R} = \sigma \vec{r}$, where $\vec{r} = \hat{i}x + \hat{j}y + \hat{k}z$ and $\vec{R} = \hat{i}X + \hat{j}Y + \hat{k}Z$.

APPENDIX B: ANALYSIS OF THE FIRST ORDER EQUATIONS

To $O(\sigma)$ in the perturbation series, one obtains

$$\hat{P}\Phi_{1} + \vec{\nabla}_{0} \cdot (\varepsilon \vec{\nabla}_{1}\Phi_{0}) + \vec{\nabla}_{1} \cdot (\varepsilon \vec{\nabla}_{0}\Phi_{0}) + f_{c(0)}(\Phi_{0}, \vec{R}, \vec{r}) = 0.$$
(B1)

To solve this equation, define a variable \bar{b} as in Eq. (3.3) that is the solution of

$$\hat{P}b_{\alpha} + \partial \varepsilon / \partial r_{\alpha} = 0, \quad \alpha = 1, 2, 3.$$
 (B2)

Here, α designates the direction x, y, or z.

Since Eq. (B1) is linear in Φ_1 , Φ_1 can be written as a sum of two terms. Define ψ such that

$$\Phi_1 = \vec{b} \cdot \vec{\nabla}_1 \Phi^* + \psi. \tag{B3}$$

This implies

$$\hat{P}\Phi_1 = \hat{P}\vec{b} \cdot \vec{\nabla}_1 \Phi^* + \hat{P}\psi. \tag{B4}$$

Since Φ^* is independent of \vec{r} , $\vec{\nabla}_0 \Phi^* = \vec{0}$. Therefore,

$$\hat{P}\Phi_1 = \vec{\nabla}_1 \Phi^* \cdot \hat{P}\vec{b} + \hat{P}\psi. \tag{B5}$$

Inserting Eq. (B5) in Eq. (B1) implies

$$\vec{\nabla}_1 \Phi^* \cdot \hat{P} \vec{b} + \hat{P} \psi + \vec{\nabla}_0 \cdot (\varepsilon \vec{\nabla}_1 \Phi_0) + \vec{\nabla}_1 \cdot (\varepsilon \vec{\nabla}_0 \Phi_0)$$

$$+ f_{c(0)}(\Phi_0, \vec{R}, \vec{r}) = 0.$$
(B6)

That $\Phi_0 = \Phi^*(\vec{R}) + \theta(\vec{R}, \vec{r})$ and $\vec{\nabla}_0 \Phi^* = \vec{0}$ implies

$$\vec{\nabla}_1 \Phi^* \cdot \hat{P} \vec{b} + \hat{P} \psi + \vec{\nabla}_0 \cdot (\varepsilon \vec{\nabla}_1 [\Phi^* + \theta]) + \vec{\nabla}_1 \cdot (\varepsilon \vec{\nabla}_0 \theta)$$

$$+ f_{c(0)}(\Phi_0, \vec{R}, \vec{r}) = 0.$$
(B7)

Collecting the above results implies

$$\vec{\nabla}_1 \Phi^* \cdot (\hat{P}\vec{b} + \vec{\nabla}_0 \varepsilon) + \hat{P}\psi + \vec{\nabla}_0 \cdot (\varepsilon \vec{\nabla}_1 \theta) + \vec{\nabla} \cdot (\varepsilon \vec{\nabla}_0 \theta)$$

$$+ f_{c(0)}(\Phi_0, \vec{R}, \vec{r}) = 0.$$
(B8)

Using Eq. (B2) yields

$$\hat{P}\psi + \vec{\nabla}_0 \cdot (\varepsilon \vec{\nabla}_1 \theta) + \vec{\nabla}_1 \cdot (\varepsilon \vec{\nabla}_0 \theta) + f_{c(0)}(\Phi_0, \vec{R}, \vec{r}) = 0. \quad (B9)$$

This justifies Eq. (3.4).

Let $b_{\alpha} = c_{\alpha} - r_{\alpha}$. With Eq. (B2), this implies

$$\hat{P}(c_{\alpha} - r_{\alpha}) + \partial \varepsilon / \partial r_{\alpha} = 0.$$

As $\hat{P}r_{\alpha} = \partial \varepsilon / \partial r_{\alpha}$, this yields $\hat{P}c_{\alpha} = 0$, justifying Eq. (3.5).

APPENDIX C: PROPERTIES OF SAMPLING FUNCTION $\ensuremath{\mathcal{W}}$

A motivation for the properties of the weighting function W is as follows. Define an averaging $\langle \dots \rangle$

$$\langle A \rangle \equiv \int d^3 r W(\vec{r}_0^* - \vec{r}) A.$$
 (C1)

When A is of the form $\vec{\nabla}_0 \cdot \vec{J}$, e.g., for $\vec{J} = \varepsilon \vec{\nabla}_0 \Phi_2$, $A = \vec{\nabla}_0 \cdot (\varepsilon \vec{\nabla}_0 \Phi_2)$,

$$\langle A \rangle \equiv \int d^3 r W \vec{\nabla}_0 \cdot \vec{J}. \tag{C2}$$

Using $W\vec{\nabla}_0 \cdot \vec{J} = \vec{\nabla}_0 \cdot (\vec{J}W) - \vec{J} \cdot \vec{\nabla}_0 W$ implies

$$\langle A \rangle \equiv \int d^3r \{ \vec{\nabla}_0 \cdot (\vec{J}W) - \vec{J} \cdot \vec{\nabla}_0 W \}. \tag{C3}$$

Using the divergence theorem, the first term becomes $\int_S dS(\vec{J}W) \cdot \hat{n}$, where \hat{n} is a unit vector normal to the surface of integration S, taken at infinity when considering nanosystem to be immersed in a virtually infinite medium. Since the integrand is zero far from the nanosystem, the integral is zero.

The second term is of the form $\int d^3r \vec{J} \cdot \vec{\nabla}_0 W$. We choose W to be nonzero in a zone of diameter $O(\sigma^{-1/2})$ and to only have spatial variations on a scale of $O(\sigma^{-1/2})$ within this zone, allowing W to mediate local averaging. For example, one may choose

$$W(\vec{r}, \vec{R}) = N \exp - \{\sigma(\vec{r}_0^* - \vec{r})^2 / \Delta^2\}$$
 (C4)

to sample \vec{r} space in the vicinity of a point $\vec{r}_0^* = \sigma^{-1} \vec{R}$. With this $\vec{\nabla}_0 W$ is $O(\sigma)$. When written in this way, W enables averaging over a zone of intermediate size, i.e., much greater than $O(\sigma^0)$ and much less than $O(\sigma^{-1})$.

Thus multiplying both sides of Eq. (3.6) with W and integrating over \vec{r} imply that all the integrands being $O(\sigma^0)$, their volume of integration is $O(\sigma^{-3})$ yielding contributions of the $O(\sigma^{-3})$. However, in accordance with the previous set of arguments, $\langle \vec{\nabla}_0 \cdot (\epsilon \vec{\nabla}_0 \Phi_2) \rangle$ is reduced to $\int d^3 r(\epsilon \vec{\nabla}_0 \Phi_2) \cdot \vec{\nabla}_0 W$. $\vec{\nabla}_0 W$ being $O(\sigma), \langle \vec{\nabla}_0 \cdot (\epsilon \vec{\nabla}_0 \Phi_2) \rangle$ becomes $O(\sigma^{-2})$ and therefore can be neglected in comparison to the other terms as $\sigma \rightarrow 0$. This justifies Eq. (3.7). A particular choice of Δ is nearest-neighbor distance between atoms in the nanosystem, i.e., a few angstrom. This makes the averaging distance $\sigma^{-1/2}\Delta$ to be a few nanometers and mediates local averaging.

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